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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable (min 10K program/erase cycles)
Delay Time tpd(1) Max	10 ns
Voltage Supply - Internal	4.5V ~ 5.5V
Number of Logic Elements/Blocks	-
Number of Macrocells	64
Number of Gates	-
Number of I/O	32
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	44-LCC (J-Lead)
Supplier Device Package	44-PLCC (16.6x16.6)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/atf1504as-10ji44

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Description

The ATF1504AS is a high-performance, high-density complex programmable logic device (CPLD) that utilizes Atmel's proven electrically-erasable memory technology. With 64 logic macrocells and up to 68 inputs, it easily integrates logic from several TTL, SSI, MSI, LSI and classic PLDs. The ATF1504AS's enhanced routing switch matrices increase usable gate count and the odds of successful pin-locked design modifications.

The ATF1504AS has up to 68 bi-directional I/O pins and four dedicated input pins, depending on the type of device package selected. Each dedicated pin can also serve as a global control signal, register clock, register reset or output enable. Each of these control signals can be selected for use individually within each macrocell.

Each of the 64 macrocells generates a buried feedback that goes to the global bus. Each input and I/O pin also feeds into the global bus. The switch matrix in each logic block then selects 40 individual signals from the global bus. Each macrocell also generates a foldback logic term that goes to a regional bus. Cascade logic between macrocells in the ATF1504AS allows fast, efficient generation of complex logic functions. The ATF1504AS contains four such logic chains, each capable of creating sum term logic with a fan-in of up to 40 product terms.

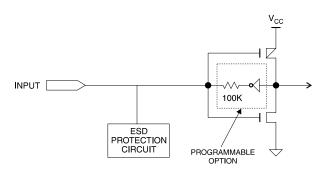
The ATF1504AS macrocell, shown in Figure 1, is flexible enough to support highly-complex logic functions operating at high speed. The macrocell consists of five sections: product terms and product term select multiplexer, OR/XOR/CASCADE logic, a flip-flop, output select and enable, and logic array inputs.



Programmable Pinkeeper Option for Inputs and I/Os

The ATF1504AS offers the option of programming all input and I/O pins so that pinkeeper circuits can be utilized. When any pin is driven high or low and then subsequently left floating, it will stay at that previous high- or low-level. This circuitry prevents unused input and I/O lines from floating to intermediate voltage levels, which causes unnecessary power consumption and system noise. The keeper circuits eliminate the need for external pull-up resistors and eliminate their DC power consumption.

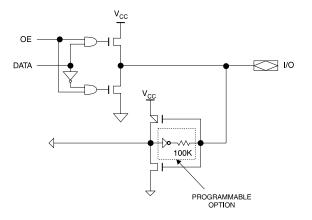
Input Diagram



Speed/Power Management

The ATF1504AS has several built-in speed and power management features. The ATF1504AS contains circuitry that automatically puts the device into a low-power standby mode when no logic transitions are occurring. This not only reduces power consumption during inactive periods, but also provides proportional power savings for most applications running at system speeds below 5 MHz. This feature may be selected as a device option.

I/O Diagram



To further reduce power, each ATF1504AS macrocell has a Reduced Power bit feature. This feature allows individual macrocells to be configured for maximum power savings. This feature may be selected as a design option.

All ATF1504AS also have an optional power-down mode. In this mode, current drops to below 10 mA. When the power-down option is selected, either PD1 or PD2 pins (or both) can be used to power-down the part. The power-down option is selected in the design source file. When enabled, the device goes into power-down when either PD1 or PD2 is high. In the power-down mode, all internal logic signals are latched and held, as are any enabled outputs.

DC and AC Operating Conditions

	Commercial	Industrial
Operating Temperature (Ambient)	0°C - 70°C	-40°C - 85°C
V _{CCINT} or V _{CCIO} (5V) Power Supply	5V ± 5%	5V ± 10%
V _{CCIO} (3.3V) Power Supply	3.0V - 3.6V	3.0V - 3.6V

DC Characteristics

Symbol	Parameter	Condition		Condition			Max	Units
I _{IL}	Input or I/O Low Leakage Current	V _{IN} = V _{CC}	$V_{IN} = V_{CC}$			-2	-10	μΑ
I _{IH}	Input or I/O High Leakage Current					2	10	
I _{OZ}	Tri-state Output Off-state Current	$V_O = V_{CC}$ or G	ND		-40		40	μΑ
			Cod Mada			105		mA
1	Power Supply Current,	V _{CC} = Max	Std Mode In			130		mA
I _{CC1}	Standby	$V_{IN} = 0, V_{CC}$	"L" Mode	Com.		10		μΑ
			Livioue	Ind.		10		μΑ
I _{CC2}	Power Supply Current, Power-down Mode	$V_{CC} = Max$ $V_{IN} = 0, V_{CC}$	"PD" Mode			1	10	mA
ı (2)	Current in Reduced-power	V _{CC} = Max	Std Power	Com		85		ma
I _{CC3} ⁽²⁾	Mode	$V_{IN} = 0$, VCC	Sid Power	Ind		105		
V	Supply Voltage	5.0V Device C	utout	Com.	4.75		5.25	V
V _{CCIO}	Supply Voltage	5.0V Device C	ruipui	Ind.	4.5		5.5	V
V _{CCIO}	Supply Voltage	3.3V Device C	utput		3.0		3.6	V
V _{IL}	Input Low Voltage				-0.3		0.8	V
V _{IH}	Input High Voltage				2.0		V _{CCIO} + 0.3	V
	Output Low Voltage (TTL)	$V_{IN} = V_{IH} \text{ or } V_{II}$	L	Com.			0.45	V
V	Output Low Voltage (TTL)	V _{CCIO} = MIN, I	_{OL} = 12 mA	Ind.				
V_{OL}	Output Low Voltage (CMOC)	$V_{IN} = V_{IH} \text{ or } V_{II}$		Com.			.2	V
	Output Low Voltage (CMOS)	$V_{CC} = MIN, I_{OL}$	$V_{CC} = MIN, I_{OL} = 0.1 \text{ mA}$.2	V
V _{OH}	Output High Voltage (TTL)		$V_{CC} = MIN, I_{OL} = 0.1 \text{ mA}$ Ind. $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CCIO} = MIN, I_{OH} = -4.0 \text{ mA}$		2.4			V

Notes: 1. Not more than one output at a time should be shorted. Duration of short circuit test should not exceed 30 sec.

Pin Capacitance

	Тур	Max	Units	Conditions
C _{IN}	8	10	pF	V _{IN} = 0V; f = 1.0 MHz
C _{I/O}	8	10	pF	V _{OUT} = 0V; f = 1.0 MHz

Note: Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested. The OGI pin (high-voltage pin during programming) has a maximum capacitance of 12 pF.



 $^{2. \ \} When \ macrocell \ reduced-power \ feature \ is \ enabled.$



Absolute Maximum Ratings*

Temperature Under Bias -40°C to +85°C

Storage Temperature -65°C to +150°C

Voltage on Any Pin with
Respect to Ground -2.0V to +7.0V⁽¹⁾

Voltage on Input Pins
with Respect to Ground
During Programming -2.0V to +14.0V⁽¹⁾

Programming Voltage with
Respect to Ground -2.0V to +14.0V⁽¹⁾

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note:

Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC} + 0.75V DC, which may overshoot to 7.0V for pulses of less than 20 ns.

AC Characteristics

		-7	7	-	10	-1	15	-2	20	-2	25	
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Units
t _{PD1}	Input or Feedback to Non-registered Output		7.5		10	3	15		20		25	ns
t _{PD2}	I/O Input or Feedback to Non-registered Feedback		7		9	3	12		16		25	ns
t _{SU}	Global Clock Setup Time	6		7		11		16		20		ns
t _H	Global Clock Hold Time	0		0		0		0		0		ns
t _{FSU}	Global Clock Setup Time of Fast Input	3		3		3		3		5		ns
t _{FH}	Global Clock Hold Time of Fast Input	0.5		0.5		1.0		1.5		2		ns
t _{COP}	Global Clock to Output Delay		4.5		5		8		10		13	ns
t _{CH}	Global Clock High Time	3		4		5		6		7		ns
t _{CL}	Global Clock Low Time	3		4		5		6		7		ns
t _{ASU}	Array Clock Setup Time	3		3		4		4		5		ns
t _{AH}	Array Clock Hold Time	2		3		4		5		6		ns
t _{ACOP}	Array Clock Output Delay		7.5		10		15		20		25	ns
t _{ACH}	Array Clock High Time	3		4		6		8		10		ns
t _{ACL}	Array Clock Low Time	3		4		6		8		10		ns
t _{CNT}	Minimum Clock Global Period		8		10		13		17		22	ns
f _{CNT}	Maximum Internal Global Clock Frequency	125		100		76.9		66		50		MHz
t _{ACNT}	Minimum Array Clock Period		8		10		13		17		22	ns
f _{ACNT}	Maximum Internal Array Clock Frequency	125		100		76.9		66		50		MHz

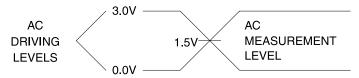


AC Characteristics (Continued)

			7	_	10		15	-2	20	-2	25	
Symbol	Parameter	Min	Max	Units								
t _{ZX1}	Output Buffer Enable Delay (Slow slew rate = OFF; V _{CCIO} = 5.0V; C _L = 35 pF)		4.0		5.0		7		9		10	ns
t _{ZX2}	Output Buffer Enable Delay (Slow slew rate = OFF; V _{CCIO} = 3.3V; C _L = 35 pF)		4.5		5.5		7		9		10	ns
t _{ZX3}	Output Buffer Enable Delay (Slow slew rate = ON; V _{CCIO} = 5.0V/3.3V; C _L = 35 pF)		9		9		10		11		12	ns
t _{XZ}	Output Buffer Disable Delay (C _L = 5 pF)		4		5		6		7		8	ns
t _{SU}	Register Setup Time	3		3		4		5		6		ns
t _H	Register Hold Time	2		3		4		5		6		ns
t _{FSU}	Register Setup Time of Fast Input	3		3		2		2		3		ns
t _{FH}	Register Hold Time of Fast Input	0.5		0.5		2		2		2.5		ns
t _{RD}	Register Delay		1		2		1		2		2	ns
t _{COMB}	Combinatorial Delay		1		2		1		2		2	ns
t _{IC}	Array Clock Delay		3		5		6		7		8	ns
$t_{\sf EN}$	Register Enable Time		3		5		6		7		8	ns
t _{GLOB}	Global Control Delay		1		1		1		1		1	ns
t _{PRE}	Register Preset Time		2		3		4		5		6	ns
t _{CLR}	Register Clear Time		2		3		4		5		6	ns
t _{UIM}	Switch Matrix Delay		1		1		2		2		2	ns
t _{RPA}	Reduced-power Adder ⁽²⁾		10		11		13		14		15	ns

Notes: 1. See ordering information for valid part numbers.

Input Test Waveforms and Measurement Levels



 t_R , $t_F = 1.5$ ns typical

^{2.} The t_{RPA} parameter must be added to the t_{LAD} , t_{LAC} , t_{TIC} , t_{ACL} , and t_{SEXP} parameters for macrocells running in the reduced-power mode.



JTAG-BST/ISP Overview

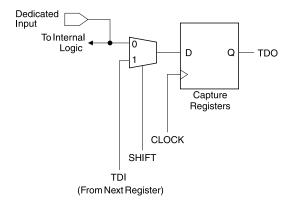
The JTAG boundary-scan testing is controlled by the Test Access Port (TAP) controller in the ATF1504AS. The boundary-scan technique involves the inclusion of a shift-register stage (contained in a boundary-scan cell) adjacent to each component so that signals at component boundaries can be controlled and observed using scan testing principles. Each input pin and I/O pin has its own boundary-scan cell (BSC) in order to support boundary scan testing. The ATF1504AS does not currently include a Test Reset (TRST) input pin because the TAP controller is automatically reset at power-up. The five JTAG modes supported include: SAMPLE/PRELOAD, EXTEST, BYPASS, IDCODE and HIGHZ. The ATF1504AS's ISP can be fully described using JTAG's BSDL as described in IEEE Standard 1149.1b. This allows ATF1504AS programming to be described and implemented using any one of the third-party development tools supporting this standard.

The ATF1504AS has the option of using four JTAG-standard I/O pins for boundary-scan testing (BST) and in-system programming (ISP) purposes. The ATF1504AS is programmable through the four JTAG pins using the IEEE standard JTAG programming protocol established by IEEE Standard 1149.1 using 5V TTL-level programming signals from the ISP interface for in-system programming. The JTAG feature is a programmable option. If JTAG (BST or ISP) is not needed, then the four JTAG control pins are available as I/O pins.

JTAG Boundary-scan Cell (BSC) Testing

The ATF1504AS contains up to 68 I/O pins and four input pins, depending on the device type and package type selected. Each input pin and I/O pin has its own boundary-scan cell (BSC) in order to support boundary-scan testing as described in detail by IEEE Standard 1149.1. A typical BSC consists of three capture registers or scan registers and up to two update registers. There are two types of BSCs, one for input or I/O pin, and one for the macrocells. The BSCs in the device are chained together through the capture registers. Input to the capture register chain is fed in from the TDI pin while the output is directed to the TDO pin. Capture registers are used to capture active device data signals, to shift data in and out of the device and to load data into the update registers. Control signals are generated internally by the JTAG TAP controller. The BSC configuration for the input and I/O pins and macrocells are shown below.

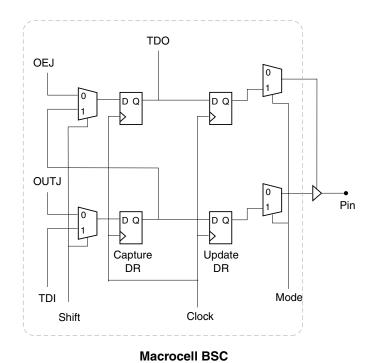
BSC Configuration for Input and I/O Pins (Except JTAG TAP Pins)



Note: The ATF1504AS has pull-up option on TMS and TDI pins. This feature is selected as a design option.

BSC Configuration for Macrocell

Pin BSC TDO Pin DQ Capture DR TDI Clock Shift

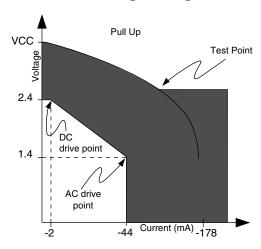




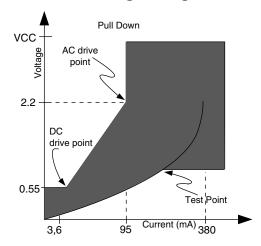
PCI Compliance

The ATF1504AS also supports the growing need in the industry to support the new Peripheral Component Interconnect (PCI) interface standard in PCI-based designs and specifications. The PCI interface calls for high current drivers, which are much larger than the traditional TTL drivers. In general, PLDs and FPGAs parallel outputs to support the high current load required by the PCI interface. The ATF1504AS allows this without contributing to system noise while delivering low output-to-output skew. Having a programmable high drive option is also possible without increasing output delay or pin capacitance. The PCI electrical characteristics appear on the next page.

PCI Voltage-to-current Curves for +5V Signaling in Pull-up Mode



PCI Voltage-to-current Curves for +5V Signaling in Pull-down Mode



PCI DC Characteristics

Symbol	Parameter	Conditions	Min	Max	Units
V _{CC}	Supply Voltage		4.75	5.25	V
V _{IH}	Input High Voltage		2.0	V _{CC} + 0.5	V
V _{IL}	Input Low Voltage		-0.5	0.8	V
I _{IH}	Input High Leakage Current	V _{IN} = 2.7V		70	μΑ
I _{IL}	Input Low Leakage Current	V _{IN} = 0.5V		-70	μΑ
V _{OH}	Output High Voltage	I _{OUT} = -2 mA	2.4		V
V_{OL}	Output Low Voltage	I _{OUT} = 3 mA, 6 mA		0.55	V
C _{IN}	Input Pin Capacitance			10	pF
C _{CLK}	CLK Pin Capacitance			12	pF
C _{IDSEL}	IDSEL Pin Capacitance			8	pF
L _{PIN}	Pin Inductance			20	nH

Leakage current is with pin-keeper off. Note:

PCI AC Characteristics

Symbol	Parameter	Conditions	Min	Max	Units
		0 < V _{OUT} ≤ 1.4	-44		mA
	Switching Current High	1.4 < V _{OUT} < 2.4	-44+(V _{OUT} - 1.4)/0.024		mA
I _{OH(AC)}	(Test High)	3.1 < V _{OUT} < V _{CC}		Equation A	mA
		V _{OUT} = 3.1V		-142	μΑ
		V _{OUT} > 2.2V	95		mA
	Switching Current Low	2.2 > V _{OUT} > 0	V _{OUT} /0.023		mA
I _{OL(AC)}	(Test Point)	0.1 > V _{OUT} > 0		Equation B	mA
		V _{OUT} = 0.71		206	mA
I _{CL}	Low Clamp Current	-5 < V _{IN} ≤ -1	-25+(V _{IN} +1)/0.015		mA
SLEW _R	Output Rise Slew Rate	0.4V to 2.4V load	0.5	3	V/ns
SLEW _F	Output Fall Slew Rate	2.4V to 0.4V load	0.5	3	V/ns

Notes: 1. Equation A: $I_{OH} = 11.9 (V_{OUT} - 5.25) * (V_{OUT} + 2.45)$ for $V_{CC} > V_{OUT} > 3.1$ V. 2. Equation B: $I_{OL} = 78.5 * V_{OUT} * (4.4 - V_{OUT})$ for 0V < $V_{OUT} < 0.71$ V.





ATF1504AS Dedicated Pinouts

	44-lead	44-lead	68-lead	84-lead	100-lead	100-lead
Dedicated Pin	TQFP	J-lead	J-lead	J-lead	PQFP	TQFP
INPUT/OE2/GCLK2	40	2	2	2	92	90
INPUT/GCLR	39	1	1	1	91	89
INPUT/OE1	38	44	68	84	90	88
INPUT/GCLK1	37	43	67	83	89	87
I/O /GCLK3	35	41	65	81	87	85
I/O/PD (1,2)	5, 19	11, 25	17, 37	20, 46	14, 44	12, 42
I/O/TDI (JTAG)	1	7	12	14	6	4
I/O/TMS (JTAG)	7	13	19	23	17	15
I/O/TCK (JTAG)	26	32	50	62	64	62
I/O/TDO (JTAG)	32	38	57	71	75	73
GND	4, 16, 24, 36	10, 22, 30, 42	6, 16, 26, 34, 38, 48, 58, 66	7, 19, 32, 42, 47, 59, 72, 82	13, 28, 40, 45, 61, 76, 88, 97	11, 26, 38, 43, 59, 74, 86, 95
V _{CCINT}	9, 17, 29, 41	3, 15, 23, 35	3, 35	3, 43	41, 93	39, 91
V _{CCIO}	_	_	11, 21, 31, 43, 53, 63	13, 26, 38, 53, 66, 78	5, 20, 36, 53, 68, 84	3, 18, 34, 51, 66, 82
N/C	-	-	_	_	1, 2, 7, 9, 24, 26, 29, 30, 51, 52, 55, 57, 72, 74, 79, 80	' ' ' '
# of Signal Pins	36	36	52	68	68	68
# User I/O Pins	32	32	48	64	64	64

OE (1, 2) Global OE Pins
GCLR Global Clear Pin
GCLK (1, 2, 3) Global Clock Pins
PD (1, 2) Power down pins

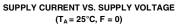
TDI, TMS, TCK, TDO JTAG pins used for boundary-scan testing or in-system programming

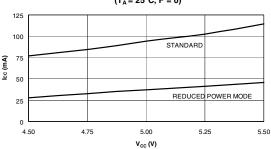
GND Ground Pins

V_{CCINT} VCC pins for the device (+5V - Internal)

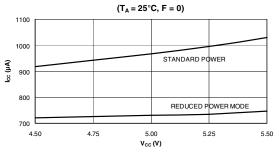
 V_{CCIO} VCC pins for output drivers (for I/O pins) (+5V or 3.3V - I/Os)



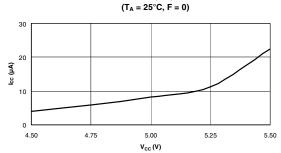




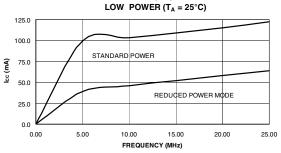
SUPPLY CURRENT VS. SUPPLY VOLTAGE PIN-CONTROLLED POWER-DOWN MODE



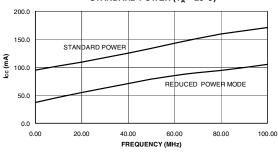
SUPPLY CURRENT VS. SUPPLY VOLTAGE LOW-POWER ("L") VERSION



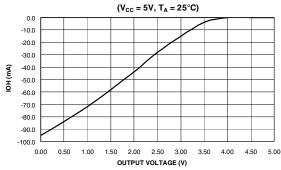
SUPPLY CURRENT VS. FREQUENCY LOW-POWER ("L") VERSION



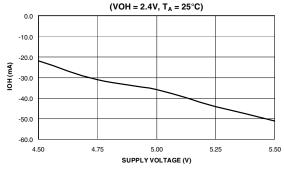
SUPPLY CURRENT VS. FREQUENCY STANDARD POWER (T_A = 25°C)



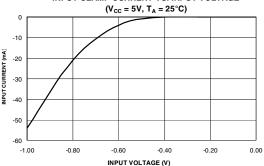
OUTPUT SOURCE CURRENT VS. OUTPUT VOLTAGE



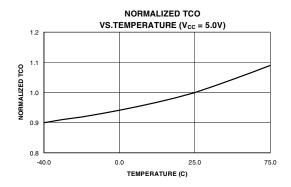
OUTPUT SOURCE CURRENT VS. SUPPLY VOLTAGE

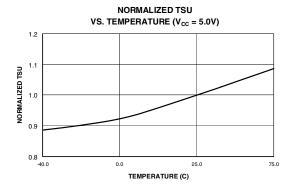


INPUT CLAMP CURRENT VS. INPUT VOLTAGE











ATF1504ASL Ordering Information

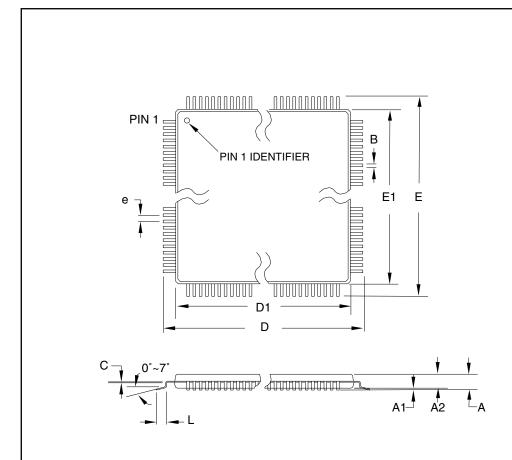
t _{PD}	t _{CO1}	f _{MAX} (MHz)	Ordering Code	Package	Operation Range
(ns)	(ns)	` '			
20	12	83.3	ATF1504ASL-20 AC44	44A	Commercial
			ATF1504ASL-20 JC44	44J	(0°C to 70°C)
			ATF1504ASL-20 JC68	68J	
			ATF1504ASL-20 JC84	84J	
			ATF1504ASL-20 QC100	100Q1	
			ATF1504ASL-20 AC100	100A	
25	15	70	ATF1504ASL-25 AI44	44A	Industrial
			ATF1504ASL-25 JI84	44J	(-40°C to +85°C)
			ATF1504ASL-25 JI68	68J	
			ATF1504ASL-25 JI84	84J	
			ATF1504ASL-25 QI100	100Q1	
			ATF1504ASL-25 AI100	100A	

Using "C" Product for Industrial

To use commercial product for Industrial temperature ranges, down-grade one speed grade from the "I" to the "C" device (7 ns "C" = 10 ns "I") and de-rate power by 30%.

Packaging Information

44A - TQFP



COMMON DIMENSIONS (Unit of Measure = mm)

SYMBOL MIN NOM MAX NOTE Α 1.20 _ Α1 0.05 0.15 Α2 0.95 1.00 1.05 12.25 D 11.75 12.00 10.00 10.10 D1 9.90 Note 2 Ε 11.75 12.00 12.25 E1 9.90 10.00 10.10 Note 2 _ В 0.30 0.45 С 0.09 0.20 L 0.45 0.75 0.80 TYP е

Notes:

- 1. This package conforms to JEDEC reference MS-026, Variation ACB.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is 0.25 mm per side. Dimensions D1 and E1 are maximum plastic body size dimensions including mold mismatch.
- 3. Lead coplanarity is 0.10 mm maximum.

10/5/2001

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2325 Orchard Parkway San Jose, CA 95131

TITLE

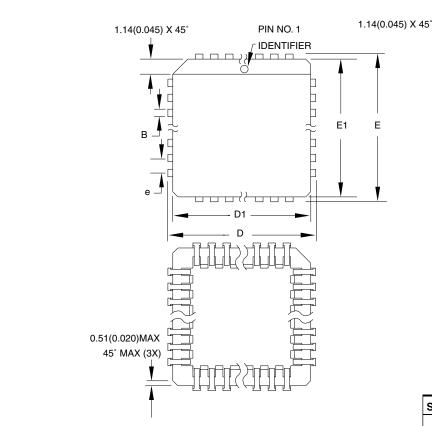
44A, 44-lead, 10 x 10 mm Body Size, 1.0 mm Body Thickness, 0.8 mm Lead Pitch, Thin Profile Plastic Quad Flat Package (TQFP)

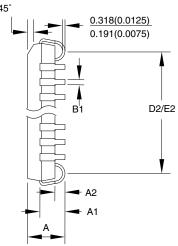
DRAWING NO.	REV.
44A	В





44J - PLCC





COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	4.191	_	4.572	
A1	2.286	_	3.048	
A2	0.508	_	_	
D	17.399	_	17.653	
D1	16.510	-	16.662	Note 2
Е	17.399	_	17.653	
E1	16.510	_	16.662	Note 2
D2/E2	14.986	_	16.002	
В	0.660	_	0.813	
B1	0.330	_	0.533	
е		1.270 TYF)	

Notes:

- 1. This package conforms to JEDEC reference MS-018, Variation AC.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is .010"(0.254 mm) per side. Dimension D1 and E1 include mold mismatch and are measured at the extreme material condition at the upper or lower parting line.
- 3. Lead coplanarity is 0.004" (0.102 mm) maximum.

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2325 Orchard Parkway San Jose, CA 95131

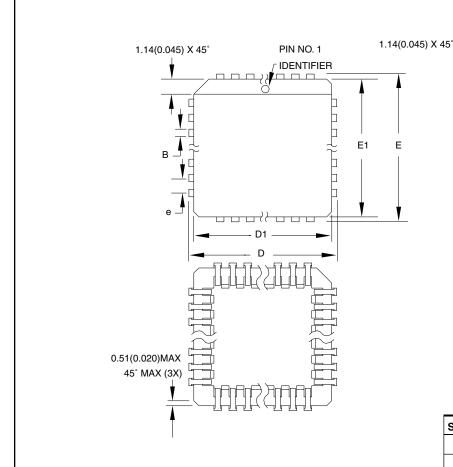
TITLE

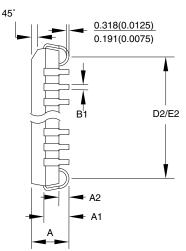
44J, 44-lead, Plastic J-leaded Chip Carrier (PLCC)

DRAWING NO. REV. 44J

В

68J - PLCC





COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	4.191	_	4.572	
A1	2.286	_	3.048	
A2	0.508	_	_	
D	25.019	_	25.273	
D1	24.130	_	24.333	Note 2
Е	25.019	_	25.273	
E1	24.130	_	24.333	Note 2
D2/E2	22.606	_	23.622	
В	0.660	-	0.813	
B1	0.330	_	0.533	
е		1.270 TYF)	

Notes:

- 1. This package conforms to JEDEC reference MS-018, Variation AE.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is .010"(0.254 mm) per side. Dimension D1 and E1 include mold mismatch and are measured at the extreme material condition at the upper or lower parting line.
- 3. Lead coplanarity is 0.004" (0.102 mm) maximum.

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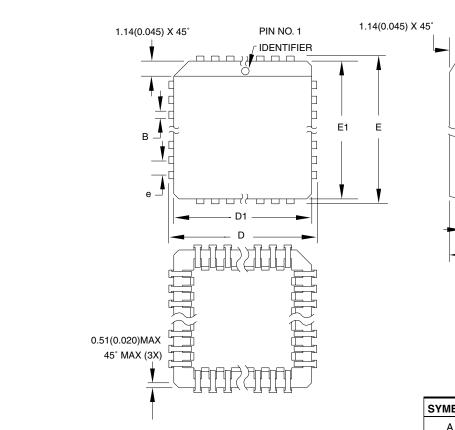
rchard Parkway se, CA 95131

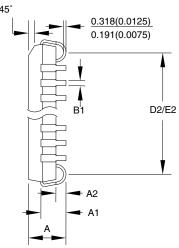
TITLE 68J, 68-lead, Plastic J-leaded Chip Carrier (PLCC) DRAWING NO. REV. 68J В





84J - PLCC





COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	4.191	_	4.572	
A1	2.286	_	3.048	
A2	0.508	_	_	
D	30.099	-	30.353	
D1	29.210	-	29.413	Note 2
E	30.099	-	30.353	
E1	29.210	_	29.413	Note 2
D2/E2	27.686	-	28.702	
В	0.660	_	0.813	
B1	0.330	-	0.533	
е		1.270 TYF)	

Notes:

- 1. This package conforms to JEDEC reference MS-018, Variation AF.
- Dimensions D1 and E1 do not include mold protrusion.
 Allowable protrusion is .010"(0.254 mm) per side. Dimension D1 and E1 include mold mismatch and are measured at the extreme material condition at the upper or lower parting line.
- 3. Lead coplanarity is 0.004" (0.102 mm) maximum.

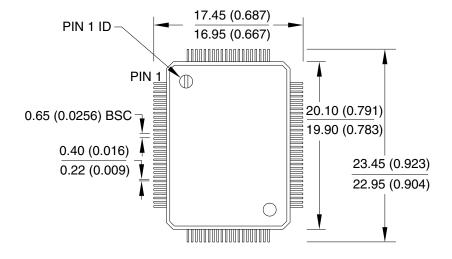
10/04/01

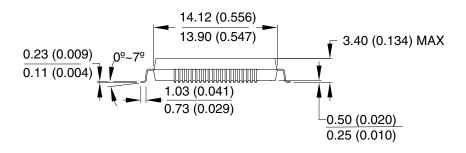
4mer	2325 Orchard San Jose, CA	Parkway
AIIIEL	San Jose, CA	95131

TITLE	DRAWING NO.	REV.
84J, 84-lead, Plastic J-leaded Chip Carrier (PLCC)	84J	В

100Q1 - PQFP

Dimensions in Millimeters and (Inches)*
*Controlling dimensions: millimeters
JEDEC STANDARD MS-022, GC-1





04/11/2001

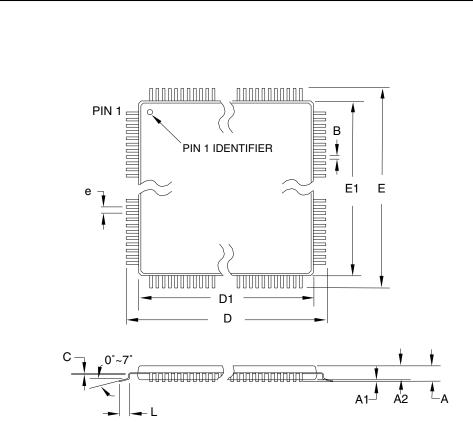
2325 Orchard Parkway San Jose, CA 95131 **TITLE 100Q1**, 100-lead, 14 x 20 mm Body, 3.2 mm Footprint, 0.65 mm Pitch, Plastic Quad Flat Package (PQFP)

DRAWING NO. REV. 100Q1 A





100A - TQFP



COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	_	_	1.20	
A1	0.05	_	0.15	
A2	0.95	1.00	1.05	
D	15.75	16.00	16.25	
D1	13.90	14.00	14.10	Note 2
E	15.75	16.00	16.25	
E1	13.90	14.00	14.10	Note 2
В	0.17	_	0.27	
С	0.09	_	0.20	
L	0.45	_	0.75	
е		0.50 TYP		

10/5/2001

Notes:

- 1. This package conforms to JEDEC reference MS-026, Variation AED.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is 0.25 mm per side. Dimensions D1 and E1 are maximum plastic body size dimensions including mold mismatch.
- 3. Lead coplanarity is 0.08 mm maximum.

		TITLE
AIMEL	2325 Orchard Parkway San Jose, CA 95131	100A , 100-lead, 14
©	San Jose, CA 95131	0.5 mm Lead Pitch,

100A, 100-lead, 14 x 14 mm Body Size, 1.0 mm Body Thickness,
0.5 mm Lead Pitch, Thin Profile Plastic Quad Flat Package (TQFP)

DRAWING NO.	REV.
100A	С



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